

PHOTOCOUPLER

KB817

GENERAL PURPOSE
HIGH ISOLATION VOLTAGE
SINGLE TRANSISTOR TYPE
PHOTOCOUPLER SERIES

FEATURES

- 1. High isolation voltage between input and output (Viso=5000 Vrms).
- 2.Compact dual-in-line package

KB817:1-channel type

- 3. Recognized by UL and CUL, file NO. E225308.
- 4. Approved by VDE 0884 Teil2(NO:40006364)

(Creepage distance between input and output:7mm or more).

5. Rohs compliant.

DESCRIPTION

- 1.The KB817 (1-channel) is optically coupled isolators containing a GaAS light emitting diode and an NPN silicon phototransistor.
- 2.The lead pitch is 2.54mm.
- 3. Solid insulation thickness between emitting diode and output phototransistor:>=0.6mm.

APPLICATIONS

- 1.Computer terminals.
- 2. Registers, copiers, automatic vending machines.
- 3. System appliances, measuring instruments.
- 4.Programmable logic controller.
- 5. Signal transmission between circuits of different potentials and impedances.



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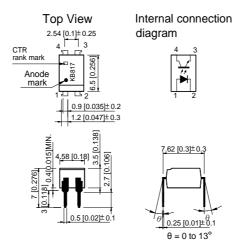


*PACKAGE DIMENSIONS (UNIT:mm)

DIP Type

TOLERANCE: ±0.5[±0.02] UNLESS OTHERWISE NOTED.

KB817



1. Anode 2. Cathode 3. Emitter 4. Collector

*Absolute Maximum Ratings (Ta=25°C)

	Parameter	Symbol	Rating	Unit
Input	Forward current	I _F	50	mA
	Reverse voltage	V_R	6	V
	Power dissipation	Р	70	mW
Output	Collector-emitter voltage	V _{CEO}	35	V
	Emitter-collector voltage	V _{ECO}	6	V
	Collector current	I _c	50	mA
	Collector power dissipation	P _c	150	mW
Total pov	ver dissipation	Ptot	200	mW
11 Isolation voltage		Viso	5000	Vrms
Operating temperature		Topr	-30~+100	°C
Storage temperature		Tstg	-55~+125	°C
¹² Soldering temperature		Tsol	260	°C

 $^{^{*1}}$ 40 to 60% RH,AC for 1 minute.

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^{*2} For 10 seconds.



*Electro-optical Characteristics

	Parameter		Symbol	Conditions	Min.	Тур.	Max.	Unit
Input	Forward voltage		VF	I _F =20mA		1.2	1.4	V
	Peak forward voltage		VFM	Iғм=0.5A			3.0	V
	Reverse current		l R	V _R =4V			10	μΑ
Output	Collector dark curr	rent	ICEO	VcE=20V,IF=0mA			10 ⁻⁷	Α
Transfer charact- eristics	*1Current transfer i	atio	CTR	IF=5mA,VcE=5V	50		600	%
	Collector-emitter s	aturation voltage	VCE(sat)	IF=20mA, Ic=1mA		0.1	0.2	٧
	Cut-off frequency		fc	VcE=5V, lc=2mA RL=100Ω,-3dB		80		KHz
	Response time	Rise time	tr	VcE=2V, lc=2mA RL=100Ω		4	18	μs
		Fall time	tf			3	18	μs

^{*1} Classification table of current transfer ratio is shown below.

$$CTR = \frac{Ic}{I_F} \times 100\%$$

Model No.	Rank mark	CTR(%)
KB817L	L	50 to 100
KB817A	А	80 to 160
KB817B	В	130 to 260
KB817C	С	200 to 400
KB817D	D	300 to 600
KB817AB	A or B	80 to 260
KB817BC	B or C	130 to 400
KB817CD	C or D	200 to 600
KB817AC	A,B or C	80 to 400
KB817BD	B,C or D	130 to 600
KB817AD	A,B,C or D	80 to 600
KB817	L,A,B,C,D or No mark	50 to 600

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Fig. 1 Current Transfer Ratio vs. Forward Current

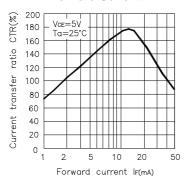


Fig. 3 Collector Current vs.

Collector-emitter Voltage

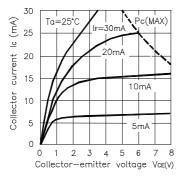


Fig. 5 Collector-emitter Saturation
Voltage vs. Ambient Temperature

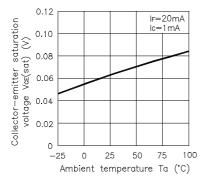


Fig. 2 Forward Current vs. Forward voltage

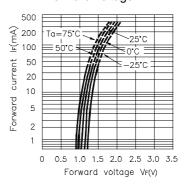


Fig. 4 Relative Current Transfer Ratio vs. Ambient Temperature

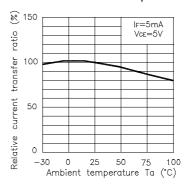
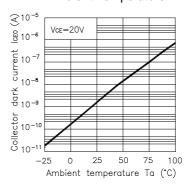


Fig. 6 Collector Dark Current vs.
Ambient Temperature



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Fig. 7 Forward Current vs.

Ambient Temperature

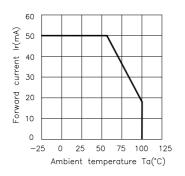


Fig. 8 Collector Power Dissipation vs.
Ambient Temperature

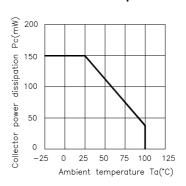
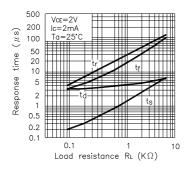


Fig. 9 Response Time vs. Load Resistance



Test Circuit for Response Time

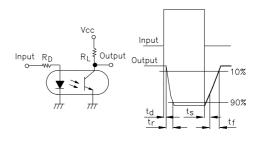
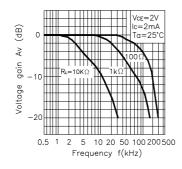
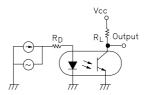


Fig. 10 Frequency Response



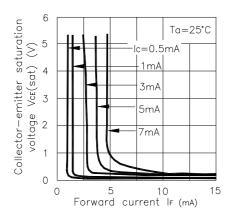
Test Circuit for Frequency Response



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Fig. 11 Collector-emitter Saturation Voltage vs. Forward Current



*NOTES ON HANDLING

1.Recommended soldering conditions (Dip soldering)

(1) Dip soldering

Temperature 260 °C or below (molten solder temperature)

Time Less than 10 seconds.

Cycle One cycle allowed to be dipped in solder including plastic mold portion.

Flux Rosin flux containing small amount of chorine

(The flux with a maximum chlorine content of 0.2 Wt % is recommended.)

(2) Cautions

Fluxes

Avoid removing the residual flux with freon-based and chlorine-based cleaning solvent.

2. Cautions regarding noise

Be aware that power is suddenly into the componment any surge current may cause damage happen, even if the voltage is within the absolute maximum ratings.

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CAUTION

Within this device there exists GaAs (Gallium Arsenide) material which is a harmful substance if ingested.

GaAs dust and fumes are toxic. Do not break, cut or pulverize the product, or use chemicals to dissolve them.

RESTRICTIONS ON PRODUCT USE

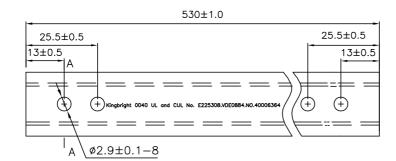
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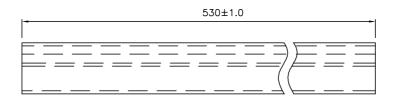


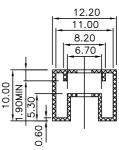
Dimension of Tube

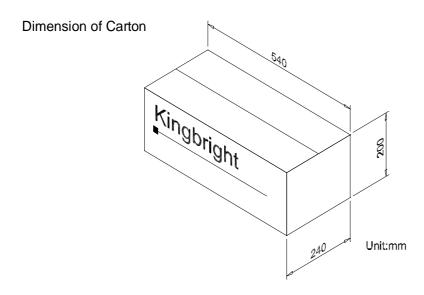
 $\label{eq:tolerance: \pm 0.4[\pm 0.012] UNLESS OTHERWISE NOTED.} Unit:mm$



A-A Side view







*ORDERING INFORMATION

Part Number	Package	Package Style	
KB817	4-pin DIP	100pcs/each tube	

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